

# 2N6052

Preferred Device

## Darlington Complementary Silicon Power Transistors

This package is designed for general-purpose amplifier and low frequency switching applications.

### Features

- High DC Current Gain —  $h_{FE} = 3500$  (Typ) @  $I_C = 5.0$  Adc
- Collector-Emitter Sustaining Voltage — @ 100 mA  
 $V_{CEO(sus)} = 100$  Vdc (Min)
- Monolithic Construction with Built-In Base-Emitter Shunt Resistors
- This is a Pb-Free Device\*

### MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	100	Vdc
Collector-Base Voltage	$V_{CB}$	100	Vdc
Emitter-Base Voltage	$V_{EB}$	5.0	Vdc
Collector Current - Continuous Peak	$I_C$	12 20	Adc
Base Current	$I_B$	0.2	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	150 0.857	W W/ $^\circ\text{C}$
Operating and Storage Temperature Range	$T_J, T_{stg}$	-65 to +200	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.17	$^\circ\text{C/W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Indicates JEDEC Registered Data.

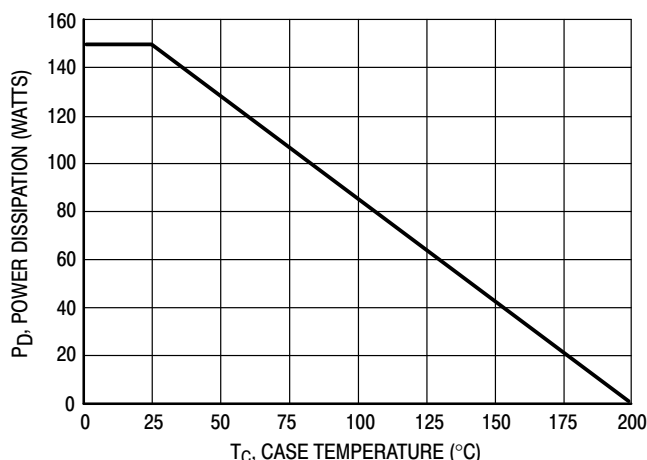


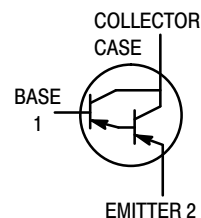
Figure 1. Power Derating



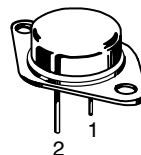
ON Semiconductor®

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## 12 AMPERE COMPLEMENTARY SILICON POWER TRANSISTOR 100 VOLTS, 150 WATTS



### MARKING DIAGRAM



TO-204AA (TO-3)  
CASE 1-07  
STYLE 1

2N6052 = Device Code  
G = Pb-Free Package  
A = Location Code  
YY = Year  
WW = Work Week  
MEX = Country of Origin

### ORDERING INFORMATION

Device	Package	Shipping
2N6052G	TO-3 (Pb-Free)	100 Units/Tray

Preferred devices are recommended choices for future use and best overall value.

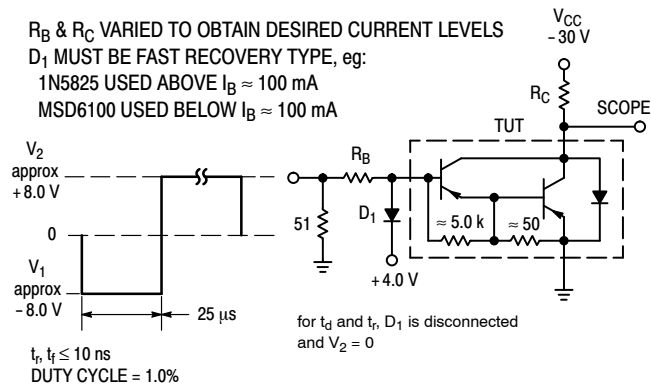
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# 2N6052

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted) (Note 2)

Characteristic	Symbol	Min	Max	Unit	
<b>OFF CHARACTERISTICS</b>					
Collector-Emitter Sustaining Voltage (Note 3)	$(I_C = 100 \text{ mAdc}, I_B = 0)$	$V_{CEO(sus)}$	100	-	Vdc
Collector Cutoff Current	$(V_{CE} = 50 \text{ Vdc}, I_B = 0)$	$I_{CEO}$	-	1.0	mAdc
Collector Cutoff Current	$(V_{CE} = \text{Rated } V_{CEO}, V_{BE(off)} = 1.5 \text{ Vdc})$ $(V_{CE} = \text{Rated } V_{CEO}, V_{BE(off)} = 1.5 \text{ Vdc}, T_C = 150^\circ\text{C})$	$I_{CEX}$	-	0.5 5.0	mAdc
Emitter Cutoff Current	$(V_{BE} = 5.0 \text{ Vdc}, I_C = 0)$	$I_{EBO}$	-	2.0	mAdc
<b>ON CHARACTERISTICS (Note 3)</b>					
DC Current Gain	$(I_C = 6.0 \text{ Adc}, V_{CE} = 3.0 \text{ Vdc})$ $(I_C = 12 \text{ Adc}, V_{CE} = 3.0 \text{ Vdc})$	$h_{FE}$	750 100	18,000 -	-
Collector-Emitter Saturation Voltage	$(I_C = 6.0 \text{ Adc}, I_B = 24 \text{ mAdc})$ $(I_C = 12 \text{ Adc}, I_B = 120 \text{ mAdc})$	$V_{CE(sat)}$	-	2.0 3.0	Vdc
Base-Emitter Saturation Voltage	$(I_C = 12 \text{ Adc}, I_B = 120 \text{ mAdc})$	$V_{BE(sat)}$	-	4.0	Vdc
Base-Emitter On Voltage	$(I_C = 6.0 \text{ Adc}, V_{CE} = 3.0 \text{ Vdc})$	$V_{BE(on)}$	-	2.8	Vdc
<b>DYNAMIC CHARACTERISTICS</b>					
Magnitude of Common Emitter Small-Signal Short Circuit Forward Current Transfer Ratio	$(I_C = 5.0 \text{ Adc}, V_{CE} = 3.0 \text{ Vdc}, f = 1.0 \text{ MHz})$	$ h_{fe} $	4.0	-	MHz
Output Capacitance	$(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 0.1 \text{ MHz})$	$C_{ob}$	-	500	pF
Small-Signal Current Gain	$(I_C = 5.0 \text{ Adc}, V_{CE} = 3.0 \text{ Vdc}, f = 1.0 \text{ kHz})$	$h_{fe}$	300	-	-

- Indicates JEDEC Registered Data.
- Pulse test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle = 2.0%.



For NPN test circuit reverse diode and voltage polarities.

Figure 2. Switching Times Test Circuit

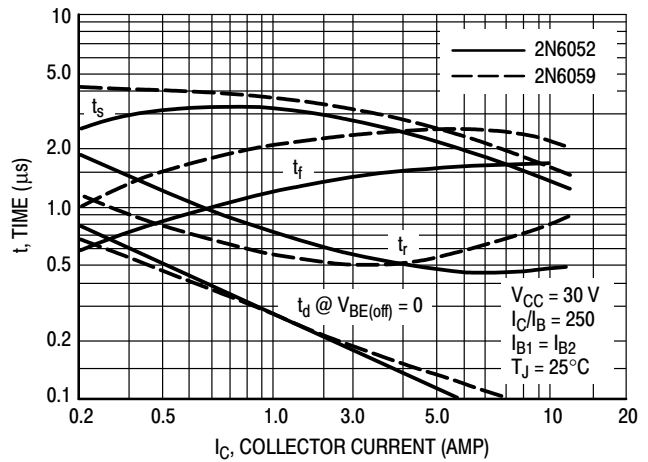


Figure 3. Switching Times

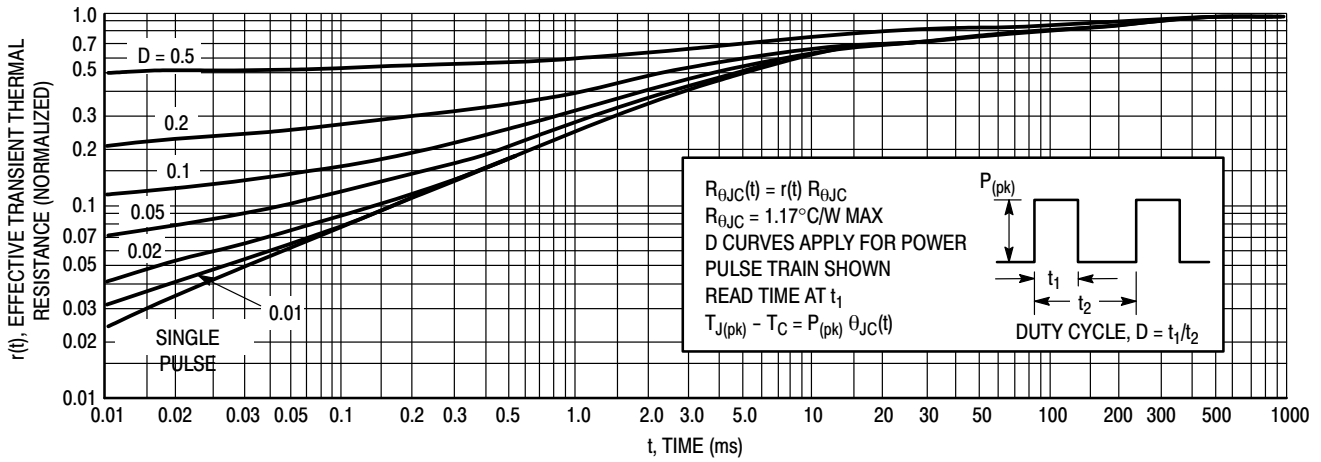


Figure 4. Thermal Response

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 5, and 6 is based on  $T_{J(pk)} = 200^{\circ}\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 200^{\circ}\text{C}$ ;  $T_{J(pk)}$  may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

ACTIVE-REGION SAFE OPERATING AREA

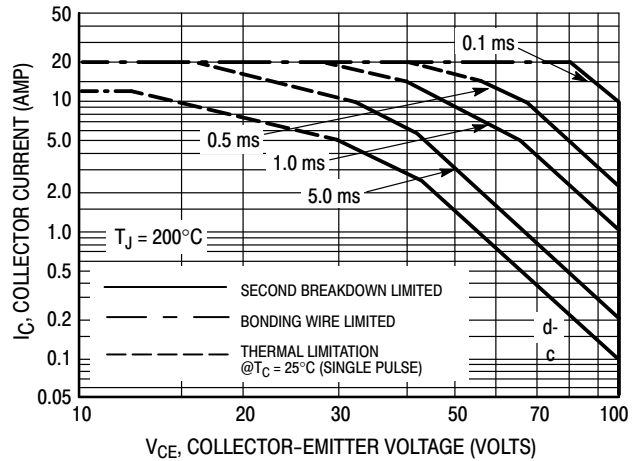


Figure 5.

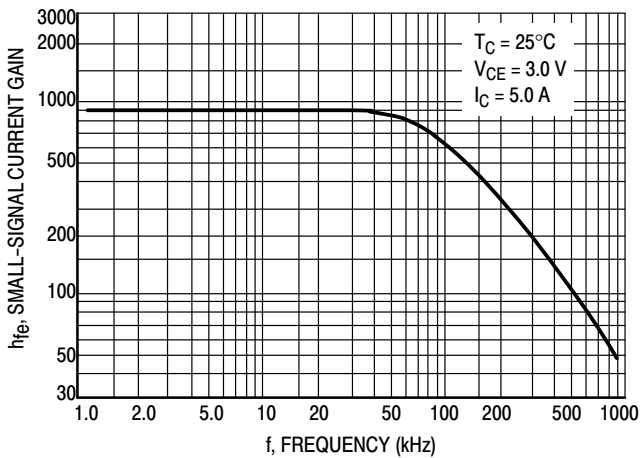


Figure 6. Small-Signal Current Gain

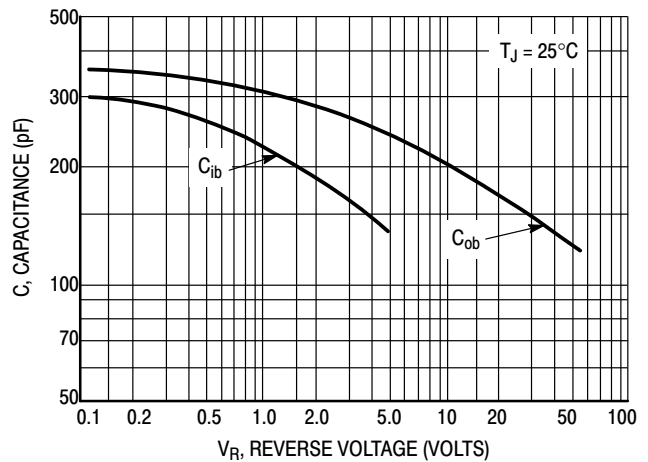


Figure 7. Capacitance

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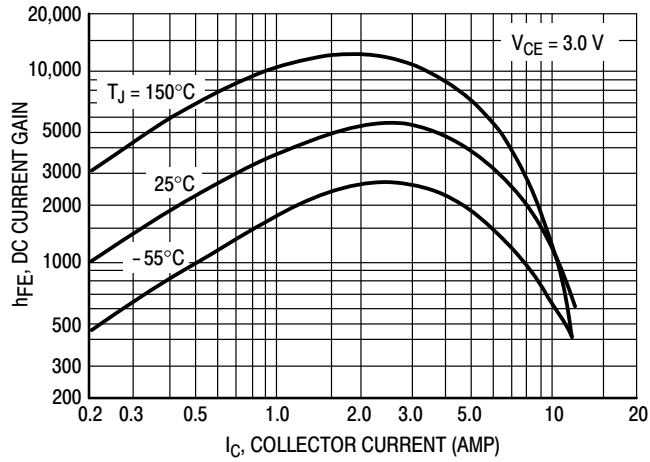


Figure 8. DC Current Gain

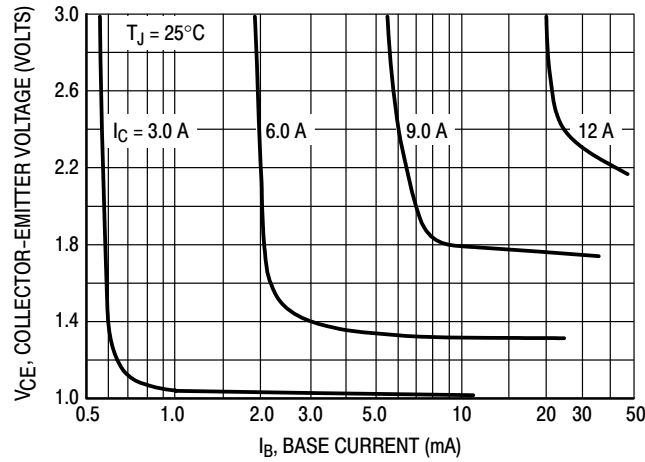


Figure 9. Collector Saturation Region

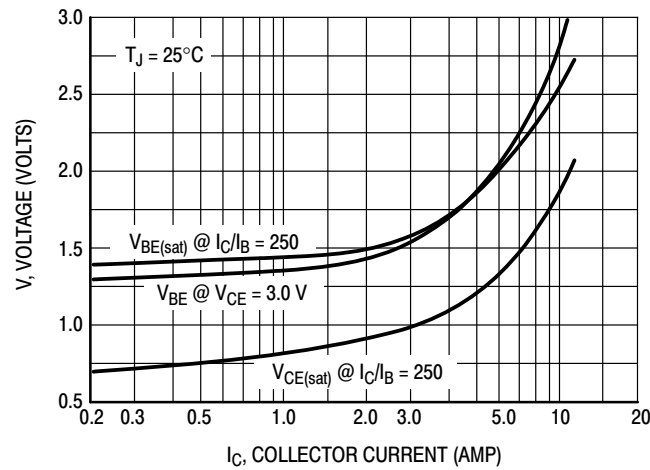
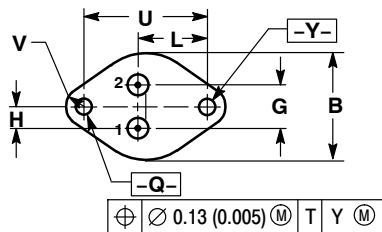
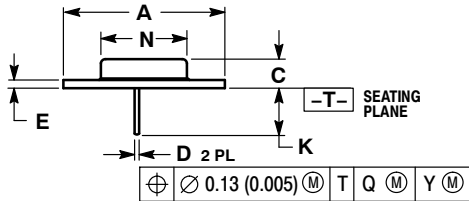


Figure 10. "On" Voltages

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## PACKAGE DIMENSIONS

TO-204 (TO-3)  
CASE 1-07  
ISSUE Z



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:

- PIN 1. BASE
  - EMITTER
- CASE: COLLECTOR

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